

RoHS Compliant Product

A suffix of "-C" specifies halogen & lead-free

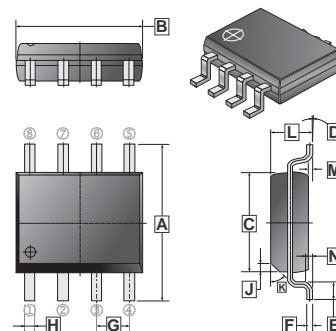
DESCRIPTION

These miniature surface mount MOSFETs utilize a high cell density trench process to provide low $R_{DS(on)}$ and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

FEATURES

- Low $R_{DS(on)}$ provides higher efficiency and extends battery life.
- Low thermal impedance copper leadframe SOP-8 saves board space.
- Fast switching speed.
- High performance trench technology.

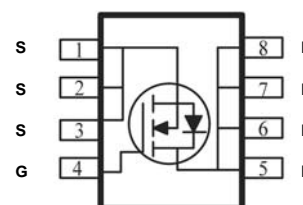
SOP-8



PACKAGE INFORMATION

Package	MPQ	LeadSize
SOP-8	2.5K	13' inch

REF.	Millimeter		REF.	Millimeter	
	Min.	Max.		Min.	Max.
A	5.80	6.20	H	0.35	0.49
B	4.80	5.00	J	0.375 REF.	
C	3.80	4.00	K	45°	
D	0°	8°	L	1.35	1.75
E	0.40	0.90	M	0.10	0.25
F	0.19	0.25	N	0.25 REF.	
G	1.27 TYP.				



MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Ratings	Unit	
Drain-Source Voltage	V_{DS}	30	V	
Gate-Source Voltage	V_{GS}	± 20	V	
Continuous Drain Current ¹	$I_D @ T_A = 25^\circ\text{C}$	9.4	A	
	$I_D @ T_A = 70^\circ\text{C}$	7.4	A	
Pulsed Drain Current ²	I_{DM}	30	A	
Continuous Source Current (Diode Conduction) ¹	I_S	1.6	A	
Total Power Dissipation ¹	$P_D @ T_A = 25^\circ\text{C}$	3.1	W	
	$P_D @ T_A = 70^\circ\text{C}$	2	W	
Operating Junction & Storage Temperature Range	T_J, T_{STG}	-55 ~ 150	$^\circ\text{C}$	
THERMAL RESISTANCE RATINGS				
Maximum Junction to Ambient ^a	$t \leq 10$ sec	$R_{\theta JA}$	50	$^\circ\text{C} / \text{W}$
	Steady State		92	$^\circ\text{C} / \text{W}$

Notes:

- 1 Surface Mounted on 1" x 1" FR4 Board.
- 2 Pulse width limited by maximum junction temperature.

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test conditions
Static						
Gate-Threshold Voltage	$V_{GS(th)}$	1	-	-	V	$V_{DS} = V_{GS}$, $I_D = 250\mu\text{A}$
Gate-Body Leakage	I_{GSS}	-	-	± 100	nA	$V_{DS} = 0\text{V}$, $V_{GS} = \pm 20\text{V}$
Zero Gate Voltage Drain Current	I_{DSS}	-	-	1	μA	$V_{DS} = 24\text{V}$, $V_{GS} = 0\text{V}$
		-	-	25	μA	$V_{DS} = 24\text{V}$, $V_{GS} = 0\text{V}$, $T_J = 55^\circ\text{C}$
On-State Drain Current ¹	$I_{D(on)}$	20	-	-	A	$V_{DS} = 5\text{V}$, $V_{GS} = 10\text{V}$
Drain-Source On-Resistance ¹	$R_{DS(ON)}$	-	-	22	m Ω	$V_{GS} = 10\text{V}$, $I_D = 9.2\text{A}$
		-	-	30		$V_{GS} = 4.5\text{V}$, $I_D = 7\text{A}$
Forward Transconductance ¹	g_{fs}	-	40	-	S	$V_{DS} = 15\text{V}$, $I_D = 9.2\text{A}$
Diode Forward Voltage	V_{SD}	-	0.7	-	V	$I_S = 2.3\text{A}$, $V_{GS} = 0\text{V}$
Dynamic ²						
Total Gate Charge	Q_g	-	4.0	-	nC	$I_D = 7\text{A}$ $V_{DS} = 10\text{V}$ $V_{GS} = 4.5\text{V}$
Gate-Source Charge	Q_{gs}	-	1.1	-		
Gate-Drain Charge	Q_{gd}	-	1.4	-		
Input Capacitance	C_{ISS}	-	720	-	pF	f = 1 MHz $V_{DS} = 15\text{V}$ $V_{GS} = 0\text{V}$
Output Capacitance	C_{OSS}	-	165	-		
Reverse Transfer Capacitance	C_{RSS}	-	60	-		
Turn-On Delay Time	$T_{d(on)}$	-	16	-	nS	$V_{DD} = 10\text{V}$ $I_D = 1\text{A}$ $V_{GEN} = 10\text{V}$ $R_L = 6\Omega$
Rise Time	T_r	-	5	-		
Turn-Off Delay Time	$T_{d(off)}$	-	23	-		
Fall Time	T_f	-	3	-		

Notes:

- 1 Pulse test : $PW \leq 300\mu\text{s}$ duty cycle $\leq 2\%$.
- 2 Guaranteed by design, not subject to production testing.

CHARACTERISTICS CURVE

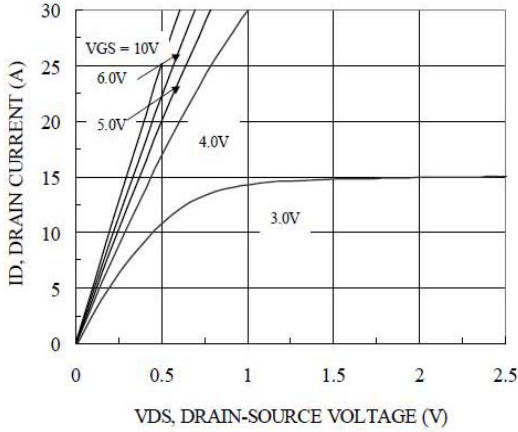


Figure 1. On-Region Characteristics

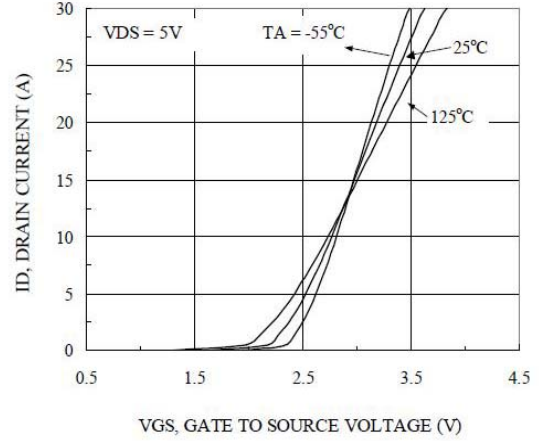


Figure 2. Body Diode Forward Voltage Variation with Source Current and Temperature

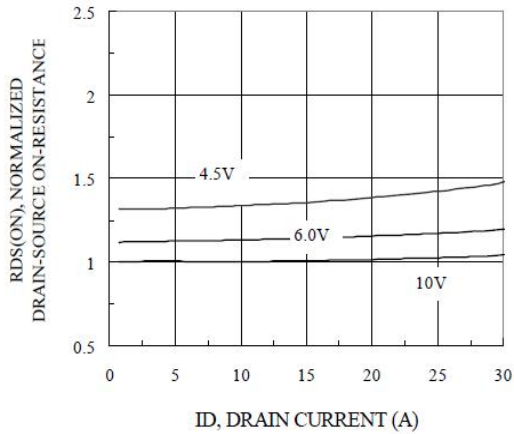


Figure 3. On Resistance Vs Vgs Voltage

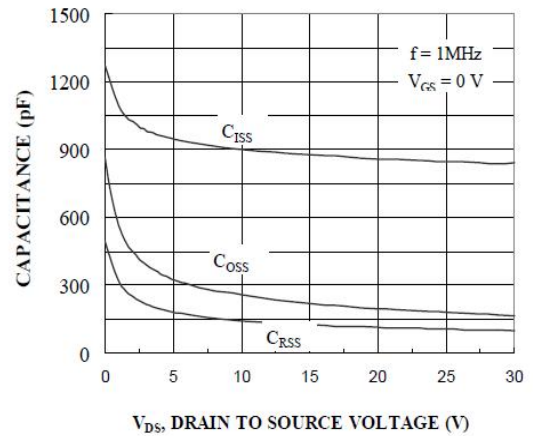


Figure 4. Capacitance Characteristics

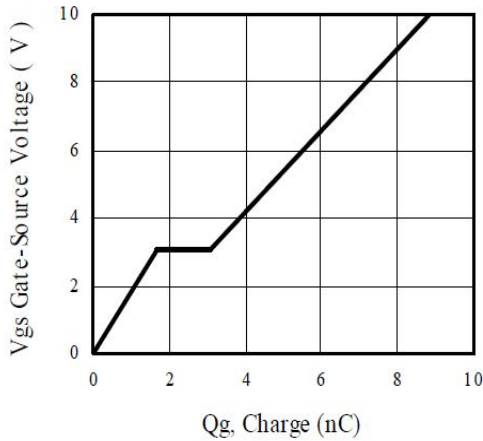


Figure 5. Gate Charge Characteristics

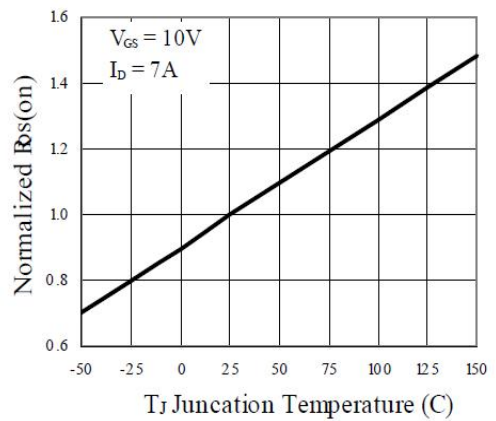


Figure 6. On-Resistance Variation with Temperature

CHARACTERISTICS CURVE

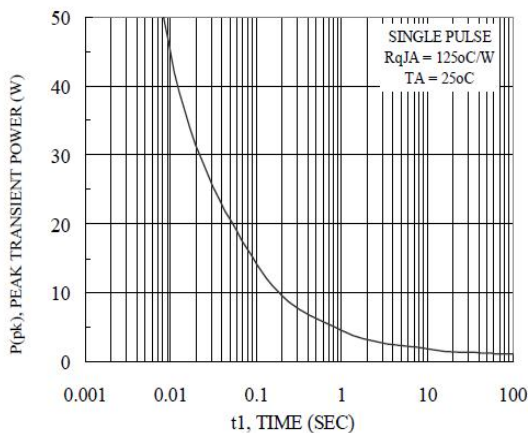
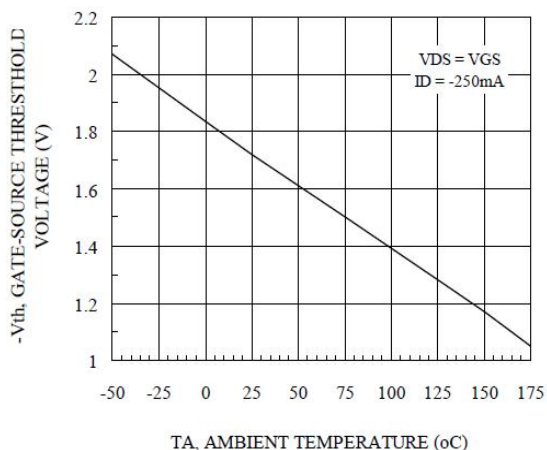
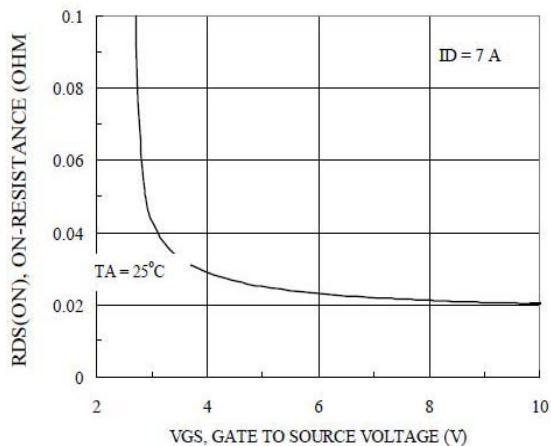
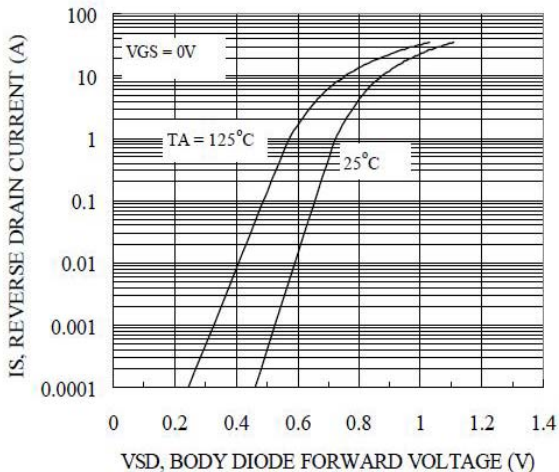


Figure 9. Vth Gate to Source Voltage Vs Temperature

Figure 10. Single Pulse Maximum Power Dissipation

Normalized Thermal Transient Junction to Ambient

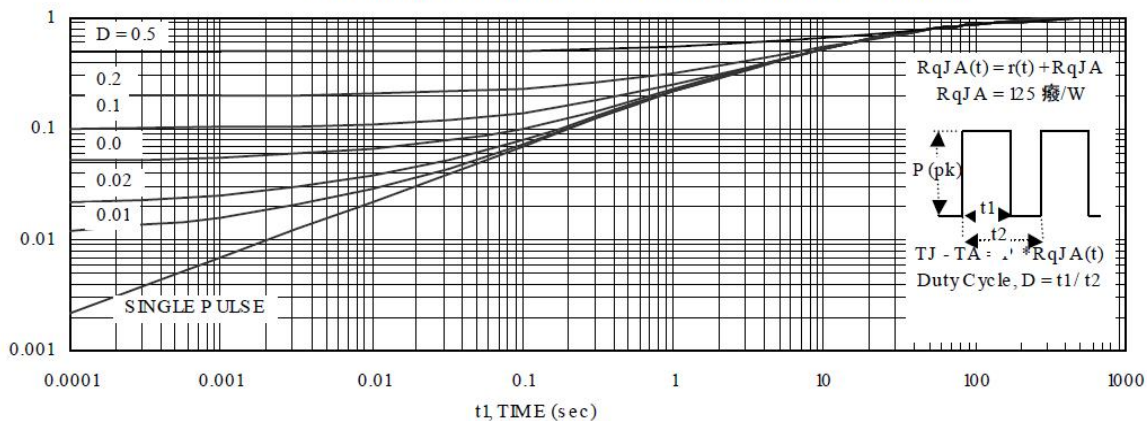


Figure 11. Transient Thermal Response Curve